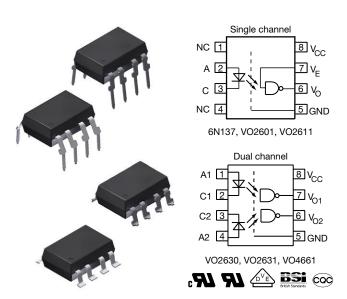


Vishay Semiconductors

High Speed Optocoupler, Single and Dual, 10 MBd



DESCRIPTION

The 6N137, VO2601, and VO2611 are single channel 10 MBd optocouplers utilizing a high efficient input LED coupled with an integrated optical photodiode IC detector. The detector has an open drain NMOS-transistor output, providing less leakage compared to an open collector Schottky clamped transistor output. The VO2630, VO2631, and VO4661 are dual channel 10 MBd optocouplers. For the single channel type, an enable function on pin 7 allows the detector to be strobed. The internal shield provides a guaranteed common mode transient immunity of 5 kV/µs for the VO2601 and VO2631 and 15 kV/µs for the VO2611 and VO4661. The use of a 0.1 µF bypass capacitor connected between pin 5 and 8 is recommended.

FEATURES

• Choice of CMR performance of 15 kV/µs, 5 kV/µs, and 1000 V/µs



- High speed: 10 MBd typical
- +5 V CMOS compatibility
- Pure tin leads



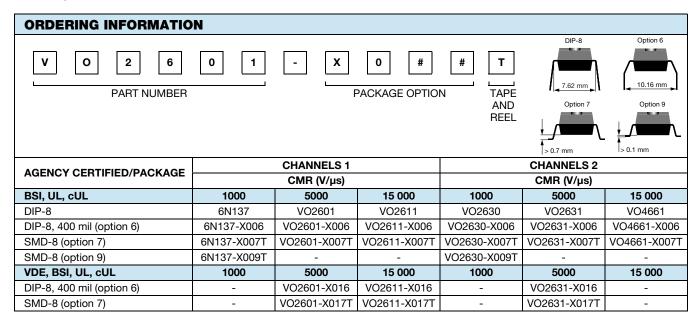
- Guaranteed AC and DC performance over temperature
- Meets IEC 60068-2-42 (SO₂) and IEC 60068-2-43 (H₂S) requirements
- Low input current capability of 5 mA
- Material categorization: for definitions of compliance please see www.vishay.com/doc?99912

APPLICATIONS

- Microprocessor system interface
- PLC, ATE input / output isolation
- Computer peripheral interface
- Digital fieldbus isolation: CC-link, DeviceNet, profibus, SDS
- High speed A/D and D/A conversion
- AC plasma display panel level shifting
- Multiplexed data transmission
- Digital control power supply
- · Ground loop elimination, noise isolation

AGENCY APPROVALS

- UL1577
- cUL
- DIN EN 60747-5-5 (VDE 0884-5) available with option 1
- BS EN 60950-1
- CQC GB8898-2011, GB4943.1-2011





6N137, VO2601, VO2611, VO2630, VO2631, VO4661

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| TRUTH TABLE (positive logic) | | | | | |
|------------------------------|--------|--------|--|--|--|
| LED | ENABLE | OUTPUT | | | |
| On | Н | L | | | |
| Off | Н | Н | | | |
| On | L | Н | | | |
| Off | L | Н | | | |
| On | NC | L | | | |
| Off | NC | Н | | | |

| PARAMETER | CONDITIONS | SYMBOL | VALUE | UNIT |
|---|---------------|-------------------|-------------------------|------|
| INPUT | | | | |
| Average forward current (single channel) | | I _F | 20 | mA |
| Average forward current (per channel for dual channel) | | I _F | 15 | mA |
| Reverse input voltage | | V _R | 5 | V |
| Enable input voltage | | V _E | V _{CC} + 0.5 V | V |
| Enable input current | | I _E | 5 | mA |
| Surge current | t = 100 μs | I _{FSM} | 200 | mA |
| Output power dissipation (single channel) | | P _{diss} | 35 | mW |
| Output power dissipation (per channel for dual channel) | | P _{diss} | 25 | mW |
| OUTPUT | | | <u> </u> | |
| Supply voltage | 1 min maximum | V _{CC} | 7 | V |
| Output current | | Io | 50 | mA |
| Output voltage | | V _O | 7 | V |
| Output power dissipation (single channel) | | P _{diss} | 85 | mW |
| Output power dissipation (per channel for dual channel) | | P _{diss} | 60 | mW |
| COUPLER | | | <u> </u> | |
| Storage temperature | | T _{stg} | -55 to +150 | °C |
| Operating temperature | | T _{amb} | -40 to +100 | °C |
| Lead solder temperature | for 10 s | | 260 | °C |
| Solder reflow temperature | | | 260 | °C |

Note

• Stresses in excess of the absolute maximum ratings can cause permanent damage to the device. Functional operation of the device is not implied at these or any other conditions in excess of those given in the operational sections of this document. Exposure to absolute maximum ratings for extended periods of the time can adversely affect reliability.

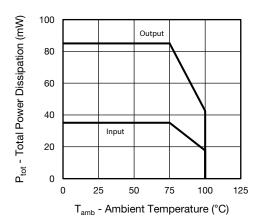


Fig. 1 - Total Power Dissipation vs. Ambient Temperature (single channel)

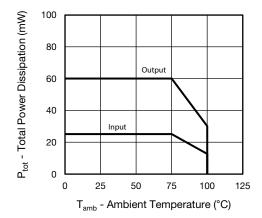


Fig. 2 - Total Power Dissipation vs. Ambient Temperature (dual channel)

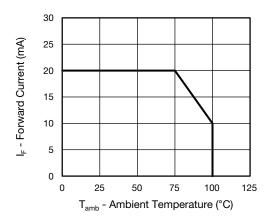


Fig. 3 - Forward Current vs. Ambient Temperature (single channel)

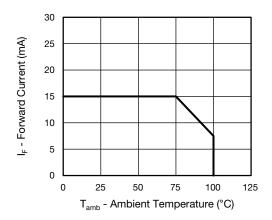


Fig. 4 - Forward Current vs. Ambient Temperature (dual channel)

| RECOMMENDED OPERATING CONDITIONS | | | | | | |
|----------------------------------|---------------------------|------------------|------|-----------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | MAX. | UNIT | |
| Operating temperature | | T _{amb} | -40 | 100 | °C | |
| Supply voltage | | V _{CC} | 4.5 | 5.5 | V | |
| Input current low level | | I _{FL} | 0 | 250 | μA | |
| Input current high level | | I _{FH} | 5 | 15 | mA | |
| Logic high enable voltage | | V_{EH} | 2 | V _{CC} | V | |
| Logic low enable voltage | | V_{EL} | 0 | 0.8 | V | |
| Output pull up resistor | | R_L | 330 | 4K | Ω | |
| Fanout | $R_L = 1 \text{ k}\Omega$ | N | - | 5 | - | |



6N137, VO2601, VO2611, VO2630, VO2631, VO4661

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| ELECTRICAL CHARACTERISTICS (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | |
|--|--|------------------|------|-------|------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT | |
| INPUT | | | | | | | |
| Input forward voltage | I _F = 10 mA | V_{F} | 1.1 | 1.4 | 1.7 | V | |
| Reverse current | V _R = 5 V | I _R | - | 0.01 | 10 | μΑ | |
| Input capacitance | $f = 1 \text{ MHz}, V_F = 0 \text{ V}$ | CI | - | 55 | - | pF | |
| OUTPUT | | | | | | | |
| High level supply current | $V_E = 0.5 \text{ V}, I_F = 0 \text{ mA}$ | I _{CCH} | - | 4.1 | 7 | mA | |
| (single channel) | $V_E = V_{CC}$, $I_F = 0$ mA | I _{CCH} | - | 3.3 | 6 | mA | |
| High level supply current (dual channel) | $I_F = 0 \text{ mA}$ | Іссн | - | 6.5 | 12 | mA | |
| Low level supply current | $V_E = 0.5 \text{ V}, I_F = 10 \text{ mA}$ | I _{CCL} | - | 4 | 7 | mA | |
| (single channel) | $V_E = V_{CC}$, $I_F = 10 \text{ mA}$ | I _{CCL} | - | 3.3 | 6 | mA | |
| Low level supply current (dual channel) | I _F = 10 mA | I _{CCL} | - | 6.5 | 12 | mA | |
| High level output current | $V_E = 2 \text{ V}, V_{CC} = 5.5 \text{ V}, I_F = 250 \mu\text{A}$ | I _{OH} | - | 0.002 | 1 | μΑ | |
| Low level output voltage | $V_E = 2 \text{ V}, I_F = 5 \text{ mA},$ I_{OL} (sinking) = 13 mA | V _{OL} | - | 0.2 | 0.6 | V | |
| Input threshold current | $V_E = 2 \text{ V}, V_{CC} = 5.5 \text{ V},$ I_{OL} (sinking) = 13 mA | I _{TH} | - | 2.4 | 5 | mA | |
| High level enable current | V _E = 2 V | I _{EH} | - | -0.6 | -1.6 | mA | |
| Low level enable current | V _E = 0.5 V | I _{EL} | - | -0.8 | -1.6 | mA | |
| High level enable voltage | | V _{EH} | 2 | - | - | V | |
| Low level enable voltage | | V_{EL} | - | - | 0.8 | V | |

Note

Minimum and maximum values are testing requirements. Typical values are characteristics of the device and are the result of engineering
evaluation. Typical values are for information only and are not part of the testing requirements.

| SWITCHING CHARACTERISTICS | | | | | | | |
|--|---|--------------------------------------|------|------|-------------------|------|--|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT | |
| Propagation delay time to high | $R_1 = 350 \Omega, C_1 = 15 pF$ | t _{PLH} | 20 | 48 | 75 ⁽¹⁾ | ns | |
| output level | h _L = 330 Ω, O _L = 13 βi | t _{PLH} | - | - | 100 | ns | |
| Propagation delay time to low | D 250 O. C 15 pE | t _{PHL} | 25 | 50 | 75 ⁽¹⁾ | ns | |
| output level | $R_L = 350 \Omega, C_L = 15 pF$ | t _{PHL} | - | - | 100 | ns | |
| Pulse width disortion | $R_L = 350 \Omega, C_L = 15 pF$ | t _{PHL} - t _{PLH} | - | 2.9 | 35 | ns | |
| Propagation delay skew | $R_L = 350 \Omega, C_L = 15 pF$ | t _{PSK} | - | 8 | 40 | ns | |
| Output rise time (10 % to 90 %) | $R_L = 350 \Omega, C_L = 15 pF$ | t _r | - | 23 | - | ns | |
| Output fall time (90 % to 10 %) | $R_L = 350 \Omega, C_L = 15 pF$ | t _f | - | 7 | - | ns | |
| Propagation delay time of enable from V _{EH} to V _{EL} | $R_L = 350 \ \Omega, \ C_L = 15 \ pF, \ V_{EL} = 0 \ V, \ V_{EH} = 3 \ V$ | t _{ELH} | - | 12 | - | ns | |
| Propagation delay time of enable from V _{EL} to V _{EH} | $R_L = 350 \ \Omega, \ C_L = 15 \ pF, \ V_{EL} = 0 \ V, \ V_{EH} = 3 \ V$ | t _{EHL} | - | 11 | - | ns | |

Notes

Over recommended temperature (T_{amb} = -40 °C to +100 °C), V_{CC} = 5 V, I_F = 7.5 mA unless otherwise specified. All typicals at T_{amb} = 25 °C, V_{CC} = 5 V.

^{(1) 75} ns applies to the 6N137 only, a JEDEC® registered specification

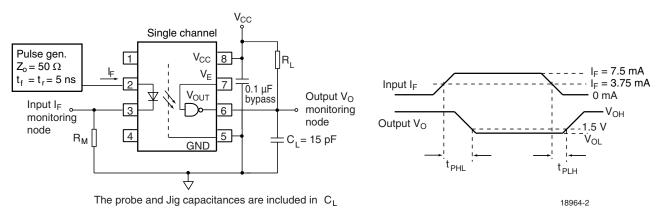


Fig. 5 - Single Channel Test Circuit for $t_{PLH},\,t_{PHL},\,t_{r}$ and t_{f}

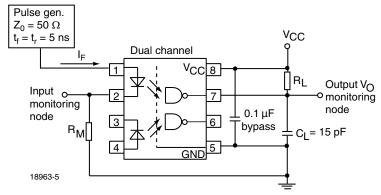


Fig. 6 - Dual Channel Test Circuit for t_{PLH} , t_{PHL} , t_{r} and t_{f}

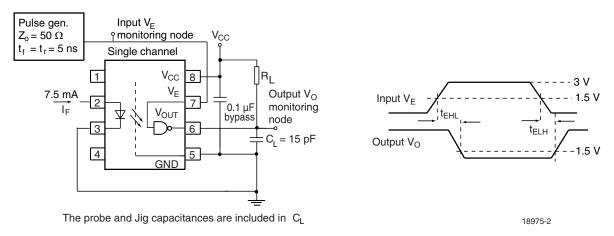


Fig. 7 - Single Channel Test Circuit for t_{EHL} , and t_{ELH}

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| COMMON MODE TRANSIENT IMMUNITY (T _{amb} = 25 °C, unless otherwise specified) | | | | | | | | |
|--|---|-----------------|--------|--------|------|------|--|--|
| PARAMETER | TEST CONDITION | SYMBOL | MIN. | TYP. | MAX. | UNIT | | |
| | $ \begin{vmatrix} V_{CM} = 10 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 0 \text{ mA}, \\ V_{O(min.)} = 2 \text{ V}, R_L = 350 \Omega, T_{amb} = 25 \text{ °C} \text{ (1)} $ | CM _H | 1000 | | | V/µs | | |
| | $ V_{CM} = 50 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 0 \text{ mA}, V_{O(min.)} = 2 \text{ V}, R_L = 350 \Omega, T_{amb} = 25 ^{\circ}C$ (2) | CM _H | 5000 | 10 000 | | V/µs | | |
| Common mode transient immunity | $ \begin{vmatrix} V_{CM} = 1 \text{ kV, } V_{CC} = 5 \text{ V, } I_F = 0 \text{ mA,} \\ V_{O(min.)} = 2 \text{ V, } R_L = 350 \Omega, T_{amb} = 25 \text{ °C } ^{(3)} $ | CM _H | 15 000 | 25 000 | | V/µs | | |
| Common mode transient immunity | $ \begin{vmatrix} V_{CM} = 10 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 7.5 \text{ mA}, \\ V_{O(max.)} = 0.8 \text{ V}, R_L = 350 \; \Omega, T_{amb} = 25 \; ^{\circ}C ^{(1)} \\ \end{vmatrix} $ | CM _L | 1000 | | | V/µs | | |
| | $ \begin{vmatrix} V_{CM} = 50 \text{ V}, V_{CC} = 5 \text{ V}, I_F = 7.5 \text{ mA}, \\ V_{O(max.)} = 0.8 \text{ V}, R_L = 350 \Omega, T_{amb} = 25 ^{\circ}\text{C} ^{(2)} \\ \end{vmatrix} $ | CM _L | 5000 | 10 000 | | V/µs | | |
| | $ \begin{vmatrix} V_{CM} = 1 \text{ kV}, V_{CC} = 5 \text{ V}, I_F = 7.5 \text{ mA}, \\ V_{O(max.)} = 0.8 \text{ V}, R_L = 350 \ \Omega, T_{amb} = 25 \ ^{\circ}\text{C} \ ^{(3)} $ | CM _L | 15 000 | 25 000 | | V/µs | | |

Notes

- ⁽¹⁾ For 6N137 and VO2630
- (2) For VO2601 and VO2631
- (3) For VO2611 and VO4661

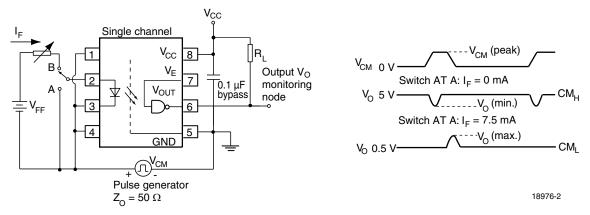


Fig. 8 - Single Channel Test Circuit for Common Mode Transient Immunity

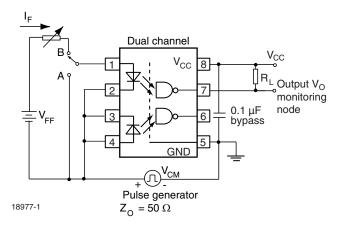


Fig. 9 - Dual Channel Test Circuit for Common Mode Transient Immunity



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| SAFETY AND INSULATION RATINGS PARAMETER | TEST CONDITION | SYMBOL | VALUE | UNIT |
|--|--|-------------------|--------------------|-------------------|
| Climatic classification | | STIVIDOL | 55 / 100 / 21 | ONIT |
| | According to IEC 68 part 1 | | | |
| Pollution degree | According to DIN VDE 0109 | | 2 | |
| Comparative tracking index | Insulation group IIIa | CTI | 175 | |
| Maximum rated withstanding isolation voltage | According to UL1577, t = 1 min | V _{ISO} | 5300 | V_{RMS} |
| Maximum transient isolation voltage | According to DIN EN 60747-5-5 | V_{IOTM} | 8000 | V _{peak} |
| Maximum repetitive peak isolation voltage | According to DIN EN 60747-5-5 | V _{IORM} | 890 | V _{peak} |
| Isolation resistance | T _{amb} = 25 °C, V _{IO} = 500 V | R _{IO} | ≥ 10 ¹² | Ω |
| isolation resistance | T _{amb} = 100 °C, V _{IO} = 500 V | R _{IO} | ≥ 10 ¹¹ | Ω |
| Output safety power | | P _{SO} | 500 | mW |
| Input safety current | | I _{SI} | 300 | mA |
| Input safety temperature | | T _S | 175 | °C |
| Creepage distance | DIP-8 | | ≥ 7 | mm |
| Clearance distance | DIP-6 | | ≥ 7 | mm |
| Creepage distance | DID 9 400 mil (antion 6) | | ≥8 | mm |
| Clearance distance | DIP-8, 400 mil (option 6) | | ≥ 8 | mm |
| Creepage distance | CMD 0 (aution 7) | | ≥ 8 | mm |
| Clearance distance | SMD-8 (option 7) | | ≥ 8 | mm |
| Creepage distance | CMD 0 (antique 0) | | ≥ 8 | mm |
| Clearance distance | SMD-8 (option 9) | | ≥ 8 | mm |
| Insulation thickness | | DTI | ≥ 0.4 | mm |

Note

TYPICAL CHARACTERISTICS (T_{amb} = 25 °C, unless otherwise specified)

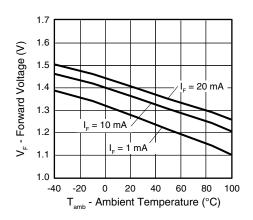


Fig. 10 - Forward Voltage vs. Ambient Temperature

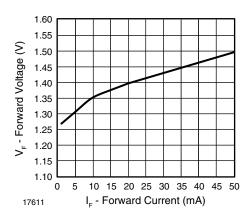


Fig. 11 - Forward Voltage vs. Forward Current

As per IEC 60747-5-5, § 7.4.3.8.2, this optocoupler is suitable for "safe electrical insulation" only within the safety ratings. Compliance with
the safety ratings shall be ensured by means of protective circuits.

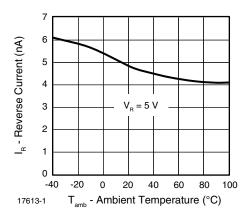


Fig. 12 - Reverse Current vs. Ambient Temperature

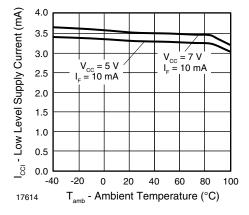


Fig. 13 - Low Level Supply Current vs. Ambient Temperature

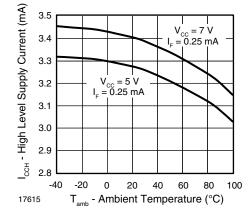


Fig. 14 - High Level Supply Current vs. Ambient Temperature

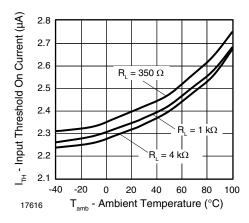


Fig. 15 - Input Threshold On Current vs. Ambient Temperature

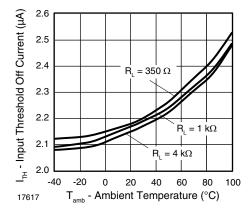


Fig. 16 - Input Threshold Off Current vs. Ambient Temperature

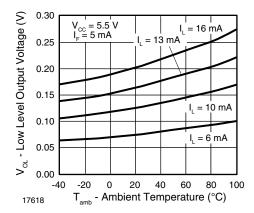


Fig. 17 - Low Level Output Voltage vs. Ambient Temperature

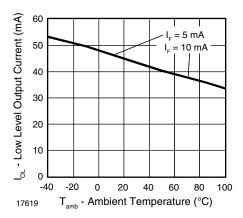


Fig. 18 - Low Level Output Current vs. Ambient Temperature

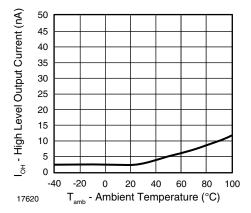


Fig. 19 - High Level Output Current vs. Ambient Temperature

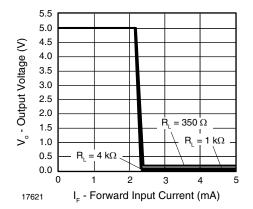


Fig. 20 - Output Voltage vs. Forward Input Current

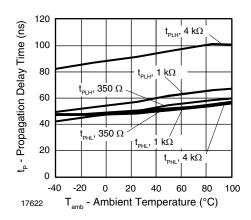


Fig. 21 - Propagation Delay vs. Ambient Temperature

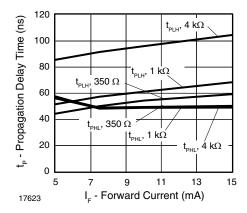


Fig. 22 - Propagation Delay vs. Forward Current

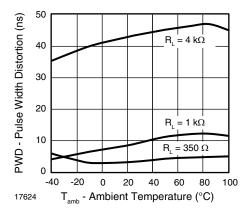


Fig. 23 - Pulse Width Distortion vs. Ambient Temperature

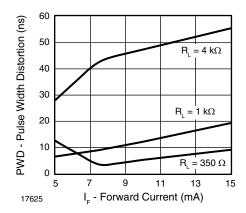


Fig. 24 - Pulse Width Distortion vs. Forward Current

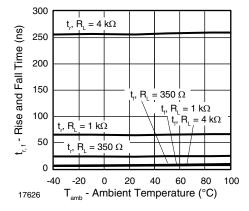


Fig. 25 - Rise and Fall Time vs. Ambient Temperature

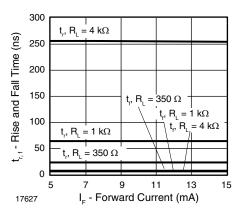


Fig. 26 - Rise and Fall Time vs. Forward Current

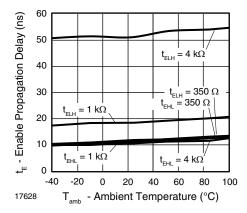


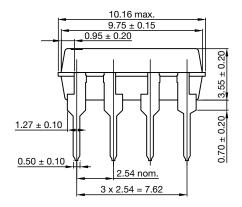
Fig. 27 - Enable Propagation Delay vs. Ambient Temperature

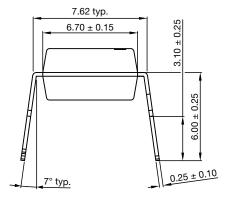


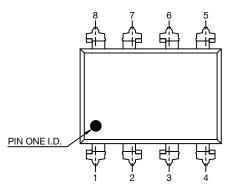
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PACKAGE DIMENSIONS (in millimeters)

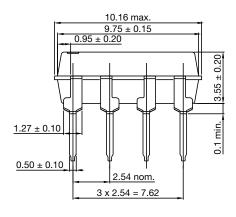
DIP-8

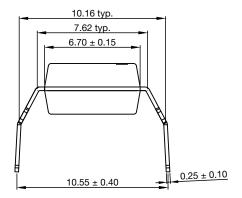


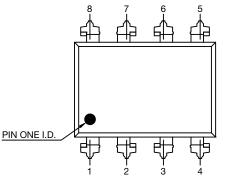




DIP-8, 400 mil (option 6)



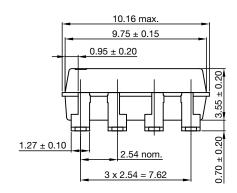


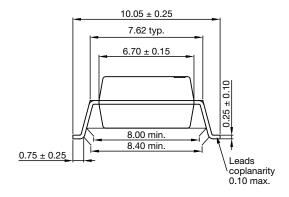




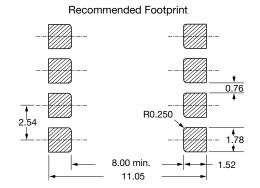
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SMD-8 (option 7)

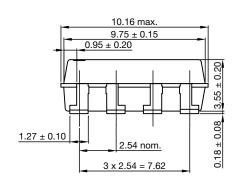


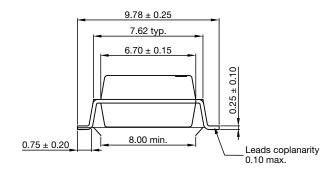


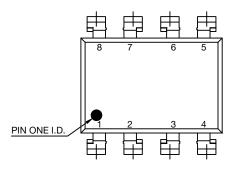
PIN ONE I.D. 2 3 4

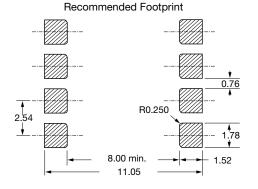


SMD-8 (option 9)









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PACKAGE MARKING

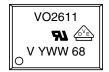


Fig. 28 - Example of VO2611-X017T

Notes

- VDE logo is only marked on option 1 parts.
- Tape and reel suffix (T) is not part of the package marking.

PACKING INFORMATION (in millimeters)

Tube

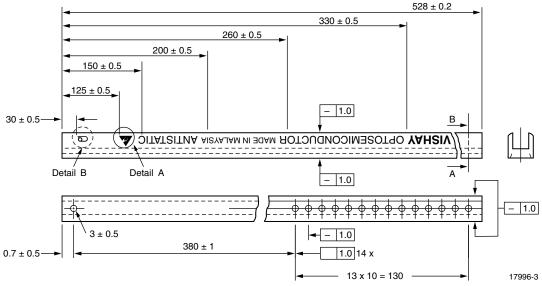


Fig. 29 - Shipping Tube Specifications for DIP-8 Packages

| DEVICES PER TUBS | | | | | | |
|------------------|------------|-----------|-----------|--|--|--|
| TYPE | UNITS/TUBE | TUBES/BOX | UNITS/BOX | | | |
| DIP-8 | 50 | 40 | 2000 | | | |

DIP-8

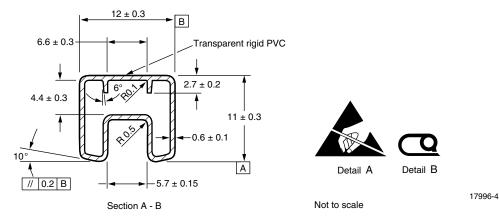


Fig. 30 - Tube Shipping Medium

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DIP-8, 400 mil (option 6)

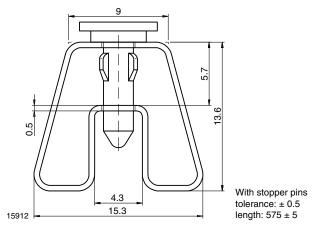


Fig. 31 - Tube Shipping Medium

Tape and Reel

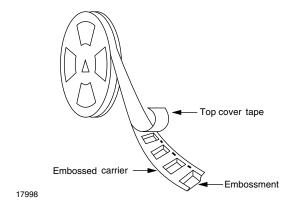


Fig. 32 - Tape and Reel Shipping Medium

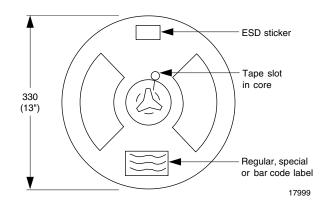


Fig. 33 - Tape and Reel Shipping Medium

SMD-8 (option 7)

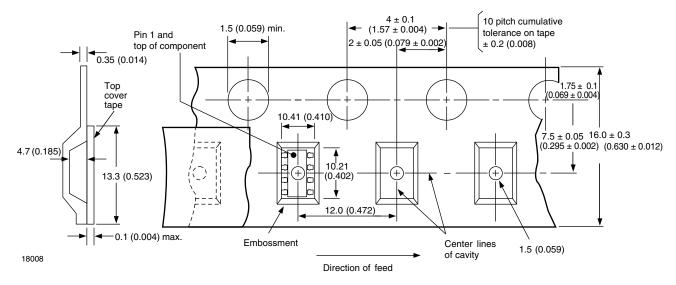


Fig. 34 - Tape and Reel Packing (1000 pieces on Reel)

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SMD-8 (option 9)

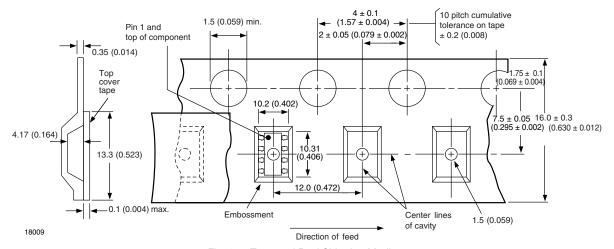


Fig. 35 - Tape and Reel Shipping Medium

SOLDER PROFILES

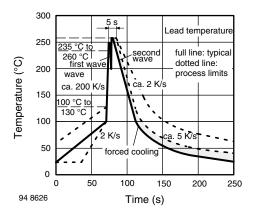


Fig. 36 - Wave Soldering Double Wave Profile According to J-STD-020 for DIP Devices

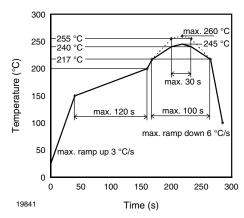


Fig. 37 - Lead (Pb)-free Reflow Solder Profile According to J-STD-020 for SMD Devices

HANDLING AND STORAGE CONDITIONS

ESD level: HBM class 2 Floor life: unlimited

Conditions: T_{amb} < 30 °C, RH < 85 %

Moisture sensitivity level 1, according to J-STD-020



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